Diode Semiconductor Device - Page 1 of 1



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Ine	closure Material:
GI	ass
0\	verall Length:
0.8	350 inches
Те	erminal Length:
1.2	250 inches
0١	verall Diameter:
0.1	187 inches
Mo	ounting Method:
Те	erminal
Fe	eatures Provided:
He	ermetically sealed case
Se	emiconductor Material:
Sil	licon
Vc	oltage Rating In Volts Per Characteristic:
25	00.0 reverse voltage, peak
Сι	urrent Rating Per Characteristic:
40	0.00 milliamperes repetitive peak forward current
Ма	aximum Operating Tempurature Per Measurement Point:
15	0.0 degrees celsius ambient air
Те	erminal Type And Quantity:
2ι	uninsulated wire lead
Sh	nelf Life:
N/	a
Ur	nit Of Measure:
De	emilitarization:
No	
Fii	ig:
A1	10a0